



#### 30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

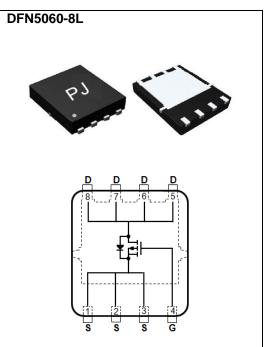
-30A

#### **Features**

- R<sub>DS(ON)</sub>, V<sub>GS</sub>@-10V,I<sub>D</sub>@-8A<20mΩ
- $R_{DS(ON)}$ ,  $V_{GS}$ @-4.5V, $I_{D}$ @-6A<32 $m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

#### **Mechanical Data**

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams



# Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	-30	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>C</sub> =25°C	l <sub>D</sub>	-30	А	
	T <sub>C</sub> =100°C		-19		
Pulsed Drain Current <sup>(Note 1)</sup>	T <sub>C</sub> =25°C	I <sub>DM</sub>	-120		
Power Dissipation	T <sub>C</sub> =25°C	Po	27	W	
	T <sub>C</sub> =100°C		11		
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	-8.5		
	T <sub>A</sub> =70°C		-6.9	A	
Power Dissipation	T <sub>A</sub> =25°C	6	2.0	W	
Power Dissipation	T <sub>A</sub> =70°C	Pb	1.3		
Operating Junction and Storage Temperature Range		$T_J$ , $T_{STG}$	-55~150	°C	
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	$R_{ heta JC}$	4.6	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





# Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-30	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-1	-1.5	-2.5		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-8A	-	17	20	mΩ	
		$V_{GS}$ =-4.5V, $I_{D}$ =-6A	-	26	32		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V,V <sub>GS</sub> =0V	-	-	-1.0	uA	
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 6)							
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-15V, I <sub>D</sub> =-5A, V <sub>GS</sub> =-4.5V (Note 1,2)	-	11	-	nC	
Gate-Source Charge	$Q_gs$		-	3.2	-		
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =-4.5V	-	3.9	-		
Input Capacitance	Ciss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	1169	-	pF	
Output Capacitance	Coss		-	180	-		
Reverse Transfer Capacitance	Crss	I=1.0IVIMZ	-	132	-		
Turn-On Delay Time	td <sub>(on)</sub>	\/ 45\/\ 40	-	5.9	-		
Turn-On Rise Time	t <sub>r</sub>	V <sub>DS</sub> =-15V,I <sub>D</sub> =-1A,	-	33	-	ns	
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =-10V, $R_{G}$ =6 $\Omega$	-	55	-		
Turn-Off Fall Time	t <sub>f</sub>		-	34	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	,		-	-	-30	А	
Diode Forward Current	I <sub>S</sub>						
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-1A,V <sub>GS</sub> =0V	-	-0.73	-1	V	

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$ =25°C.
- 4. The maximum current rating is package limited
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing





#### **TYPICAL CHARACTERISTIC CURVES**

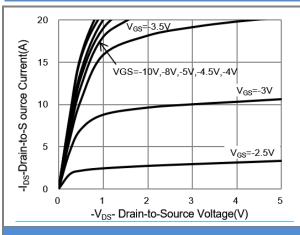
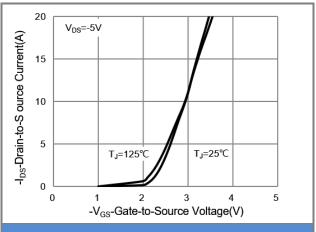


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

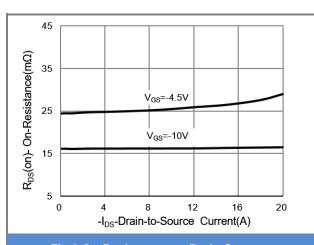


Fig.3 On-Resistance vs. Drain Current

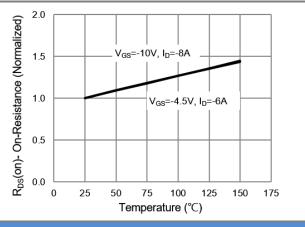


Fig.4 On-Resistance vs. Junction temperature

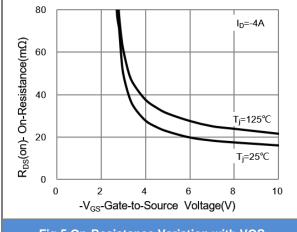
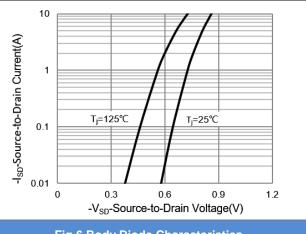


Fig.5 On-Resistance Variation with VGS.



**Fig.6 Body Diode Characteristics** 





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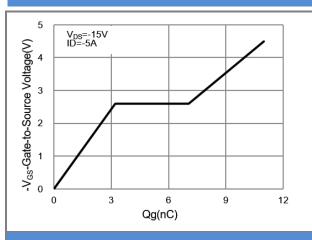


Fig.7 Gate-Charge Characteristics

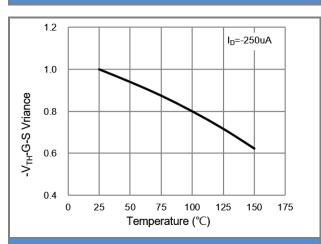


Fig.9 Threshold Voltage Variation with Temperature.

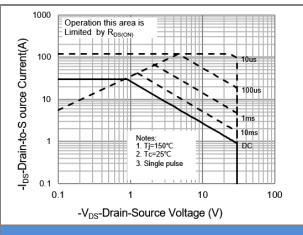


Fig.11 Maximum Safe Operating Area

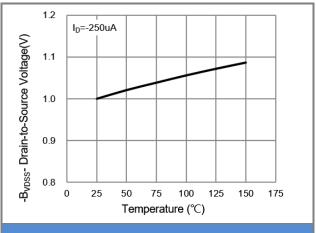


Fig.8 Breakdown Voltage Variation vs. Temperature

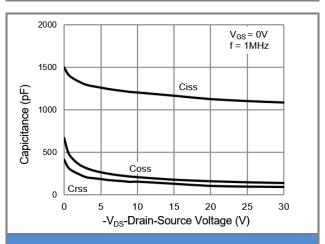


Fig.10 Capacitance vs. Drain-Source Voltage.





#### **TYPICAL CHARACTERISTIC CURVES**

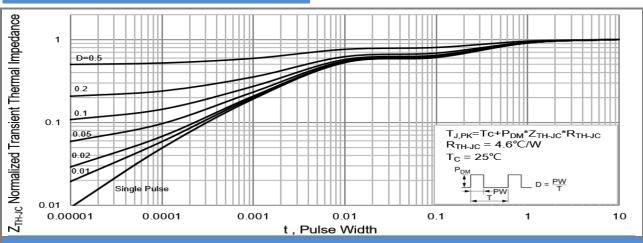


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

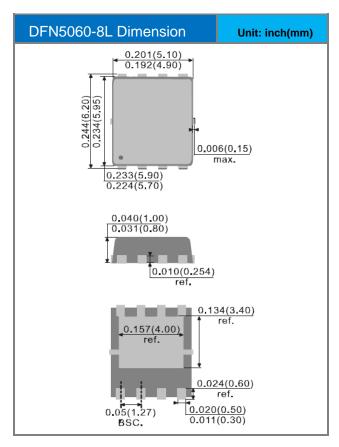


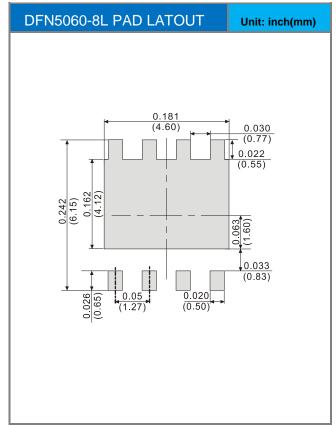


#### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	cking Type Marking	
PJQ5419_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5419	Halogen free

### **Packaging Information & Mounting Pad Layout**









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